

FORM PTO-1449					NT OF C			PHOCKET NO.	. 003330 USA/ETCH/M	APPLICATION NO.: 10/042,666					
INFORMA'				URE CATIO		remi	BNT	APPLICANT:	Han, et al.	2 0	and the second	_			
				f necess				FILING DATE	3: 1/8/2002		GROUP A				
					Ç.C	⊘¥	Υ γ υ	SPATIENT	DOCUMENTS	bener ke	<u>6</u>				
EXAMINER INITIAL	DOCUMENT NUMBER							DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE			
M	4	8	9	7	3	1	5	1/30/1990	Gupta	428	552				
_ML	4	9	3	9	3	0	8	7/3/1990	Maxfield et al.	505					
M	4	9	3	3	2	3	9	6/12/1990	Olson et al.	428	557				
M	4	9	1	0	0	9	2	3/20/1990	Olson et al.	428	5570°0	ALLY FILED			
m	5	2	4	4	8	7	5	9/14/1993	Hauser et al.	505	I I'M	OK PA			
m	5	4	7	0	8	2	0	11/28/1995	Hauser et al.	505	472	YEA	8		
m	5	8	2	4	2	0	5	10/20/1998	Foster	205	109	100			
m	5	8	3	3	8	2	9	11/10/1998	Foster	205	109				
m	6	3	0	6	2	7	6	10/23/2001	Nobe et al.	205	238				
] 					FOR	EIGN PATE	NT DOCUMENT	S					
	DOCUMENT NUMBER							DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION			
												YES	NO		
						<u> </u>									
t.::															
				<u> </u>	—	<u> </u>	ļ								
	5 (¹)	•	OT	HER	DOC	UME	ENTS	(Including A	uthor, Title, Date,	Pertinent Pa	ges, etc.)		AND WIND		
Hart, Anthony C, Alloy plating problem cracked, Nickel Magazine, June 1998								· · · · · · · · · · · · · · · · · · ·							
and the same of the same									nologies Ltd, 2002, A		R52565550043e	e8d/\$FILF/	MCrAIVco		
				April											
			/			<i>9</i> —		-			· · · · · ·				
EXAMINER		Lavute								DATE CO	DATE CONSIDERED 6/6/03				
									conformance with MPI		ine through cita	tion if not in	ı		

FILING DATE

FORM PTO-1449 U.S. DEPARTMENT OF COMMERCE DOCKET NO. 003330/ETCH/METAL/JB APPLICATION PATENT AND TRADEMARK OFFICE NO:N/A INFORMATION DISCLOSURE STATEMENT APPLICANT: Han, et al. IN AN APPLICATION FILING-DATE: Herewith GROUP ART U (Use-several-sheets-if necessary) U.S. PATENT DOCUMENTS **EXAMINER** DOCUMENT NUMBER DATE NAME **CLASS SUBCLASS** INITIAL IF APPROPRIATE m 55 06 Blackburn, et al. 3 01/13/81 M 428 7 3 ٥ 3 217 5/10/88 Sioshansi, et al. 420 m 443 9 7 3 4 5 11/27/90 Singheiser, et al 643 156 ML 5 3 6 5 8 5 6 11/22/94 Robertson, et al. m 156 643.1 3 03/12/96 Bailey, et al. 420 m 544 5 2 4 3 2 6 6 4/29/97 Baumann, et al. 315 ML 111.21 5 6 0 0 1 3 10/21/97 Dornfest, et al. 118 M 723 T 5 7 3 5 0 4 4 05/19/98 Hanawa, et al. 345 M 156 Oehrlein, et al. 5 7 9 8 0 1 6 08/25/98 ML 428 216 5 Q 8 3 5 09/07/99 Kriven, et al. 14.21 5 9 6 4 9 2 8 06 10/12/99 Tomlinson, et al 156 F-2 6 25 1 3 7 9 12/26/00 Han, et al. in 420 528 8 8 05/15/01 Hashikura, et al. FOREIGN PATENT DOCUMENTS TRANSLATION DOCUMENT NUMBER DATE COUNTRY CLASS SUBCLASS

	·										YES	NO
m.	9	8	1	4	9	8	0	04/09/98	PCT	 	х	
m	9	4	2	1	6	7	1	08/22/96	Germany			х
m	08	4	9	7	6	7	A2	06/24/98	Europe	 	х	
par	35	4	3	8	0	2	Al	06/19/87	Germany			x
ihr	20	09	6	1	7	6	A2	4/4/00	Japan	 	Abstract	
m	9	9	7	5	4	6	Al	5/3/00	Europe	 	x	-
m	43	3	3	5	7	3	A2	11/20/92	Japan		Abstract	
m	1	6	4	5	7	2	A2	6/16/00	Japan	 	х	
m	11	0	2	9	3	7	8	2/2/99	Japan		Abstract	
hir	10	0	6	7	5	5	4	03/10/98	Japan	 	Abstract	

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, etc.)

m An article entitled, "The evolution of DRAM cell technology," Solid State Technology 89-101 (May 1997), El-Kareh, et al.

m PCT Communication dated 11/25/99, European Patent Office, P.B 5818 Patentlaan, NL-2280 HV Rijswik

6/6/03 DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

EXAMINER